

LMC669 Auto-Zero

General Description

The LMC669 uses sampled-data techniques to reduce the input offset voltage (VOS) of an amplifier or system to approximately 5 μV . A four-stage comparator samples the summing node of an inverting-amplifier and generates a correction voltage that is applied to the amplifier's non-inverting input. The offset correction is independent of time, temperature, and supply voltage, and requires no initial or periodic user offset adjustments.

The user may also adjust clock frequency, sample rate, and the correction voltage's step size and magnitude.

The Auto-Zero operates on supply voltages of $\pm 8\text{V}$ to $\pm 20\text{V}$ with a quiescent current of 3 mA.

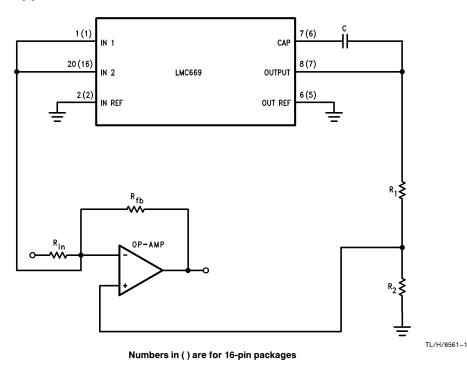
The use of the LMC669 does not limit the performance of the amplifier it is used with. Full use of the gain-bandwidth product, slew rate, and DC gain is retained.

The LMC669 can be used as a precision comparator with a latched, open drain output, or as a low-offset inverting operational amplifier for low-speed applications.

Features

- 5 microvolts typical offset voltage
- Temperature independent offset correction
- Internal or external clocking
- Automatic and continuous offset voltage correction
- High voltage CMOS—up to ±20V supplies

Typical Application



Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \mbox{Positive Supply Voltage } (\mbox{V}^+) & +22\mbox{V} \\ \mbox{Negative Supply Voltage } (\mbox{V}^-) & -22\mbox{V} \\ \mbox{Voltage of Logic Pins} & & & & & & & \\ \mbox{T1, T2, $\overline{\mbox{RESET}}$, CLK} & & & & & & & & \\ \mbox{Voltage at Inputs} & & & & & & & & \\ \mbox{-0.2V to } (\mbox{V}^+ + 0.2\mbox{V}) \\ \mbox{Voltage at Inputs} & & & & & & & \\ \mbox{-0.2V to } (\mbox{V}^+ + 0.2\mbox{V}) \\ \mbox{-0.2V to } (\mbox{V}^+$

Input Current (Note 3)
INREF, IN1 and IN2 20 mA

Power Dissipation (Note 4) 500 mW Storage Temperature $-65^{\circ}\mathrm{C}$ to $+150^{\circ}\mathrm{C}$ Lead Temp. (soldering, 10 seconds) 300°C

Operating Ranges (Notes 1 & 2)

Temperature Range $T_{MIN} \le T_A \le T_{MAX}$ LMC669D $-40^{\circ} C \le T_A \le +85^{\circ} C$ Positive Supply Voltage +8V to +20V Negative Supply Voltage -8V to -20V INREF, IN1 and IN2 Voltage (Note 5) -200 mV to +2V ESD Susceptability (Note 10) 600V

Electrical Characteristics The following specifications apply for $V^+ = +15V$, and $V^- = -15V$ unless otherwise specified. **Boldface limits apply for T_{MIN} to T_{MAX};** all other limits $T_A = T_J = 25^{\circ}C$.

Symbol	Parameter				Conditions	Typical (Note 6)	Tested Limit (Note 7)	Design Limit (Note 8)	Units
V _{OS}	Maximum Input Offset Voltage	l	LMC669BIN, BIM LMC669BCN, BCM		Signal applied to both IN1 & IN2, T _{CLK} = 50 μs, V _{INREF} = 0V, 0.5V	±5	± 25 ± 25		μV
	(Note 9)	LMC669CIN, CIM LMC669CCN, CCM				± 10	± 50 ± 50		
		LMC	LMC669CD			±5	± 25		
V _{OS}	Maximum Input Offset Voltage (Note 9)	LMC669BIN, BIM LMC669BCN, BCM			Signal applied only to IN1 or IN2, T _{CLK} = 50 μs, V _{INREF} = 0V	±10	± 50 ± 50		μV
			MC669CIN, CIM MC669CCN, CCM			±20	± 100 ± 100		
		LMC	669CD			±10	± 50		
l _b	Maximum Input		IN2		Clock Off	1	100		pА
	Bias Current					400			pА
			IN1 or IN1 & IN2			5	100		pА
						40		75	nA
$\frac{\Delta V_{OS}}{\Delta T}$	Average Input Offset Drift				0.1			μV/°C	
$V_{\text{IN1}}, V_{\text{IN2}}$	IN1 & IN2 Input Voltage Range (Note 5)		ı	min		-200	0		mV
				max		+2.0	+0.5		V
V _{IN REF}	IN REF Input Voltage Range (Note 5)			min		-200	0		mV
				max		+2.0	+0.5		V
$V_{\text{OUT REF}}$	Range			min		-100			mV
				max		+100			mV
PSRR	Power Supply Rejection Ratio				120			dB	
V _{OUT}	Integrator Output Voltage Range				±14	±12	± 11	V	
V _{CO}	Comparator Open-Drain		Low (max)	Sink Current = 1.0 mA	0.25	0.4		V	
	Output Voltage Range			High (min)		25	20		19
ls+	Maximum Positive Supply Current				RESET Low,	3.2	6.0		mA
				T _{CLK} = 50 μs		10.0			

Electrical Characteristics The following specifications apply for $V^+=+15V$, and $V^-=-15V$ unless otherwise specified. **Boldface limits apply for T_{MIN} to T_{MAX};** all other limits $T_A=T_J=25^{\circ}C$. (Continued)

, , , , , , , , , , , , , , , , , , , ,								
Symbol	Parameter			Conditions	Typical (Note 6)	Tested Limit (Note 7)	Design Limit (Note 8)	Units
I _S -	Maximum Negative Supply Current			RESET Low, T _{CLK} = 50 μs	2.0	5.0		- mA
						7.0		
f _S	Maximum Sample Rate			RESET Low, Internal Clock	100	66.6	56	kHz
fcLK	Clock Frequency Range	ock Frequency Range min			100		100	Hz
			max		100		100	kHz
T _R	Minimum RESET Pulse Width				80	150	175	ns
V _{TH}	Digital Input Threshold Voltage	T1, T2, RESET	High (min)		2.9	3.5		V
			Low (max)		2.9	1.5		V
		CLK	High (min)		3.5	4.0		٧
			Low (max)		1.5	1.0		V
I _{D IN}	T1, T2, RESET, & CLK Maximum Digital Input Current		High		1.0			pА
						1.0		μΑ
			Low		1.0			pА
						1.0		μΑ

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its specified operating conditions.

Note 2: All voltages are with respect to AGND.

Note 3: This input current will exist only when an input is driven to a voltage greater than $(V^+ + 0.2V)$ or less than -0.2V. It is due to internal diode clamps at the inputs turning on. If the current is limited to 20 mA, the overdrive will not be harmful to the LMC669.

Note 4: The typical junction-to-ambient thermal resistance (θ_{JA}) of the 16 pin J package is 80°C/W.

Note 5: If input currents are limited, input voltages may be driven beyond these limits and the device will still be functional. The comparator output will be correct as long as the voltage on either the INREF pin or the two input IN1 & IN2 pins is between -200 mV and +2V.

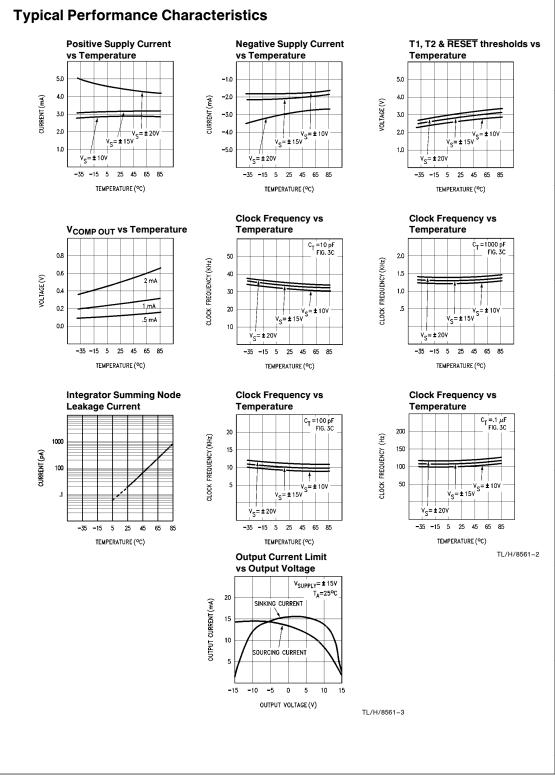
Note 6: Typicals are at 25°C and represent most likely parametric norm.

Note 7: Guaranteed and 100% tested.

Note 8: Guaranteed, but not 100% production tested. These limits are not used to calculate outgoing quality levels.

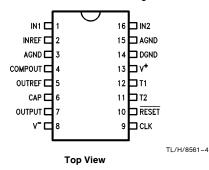
Note 9: The LMC669CD exhibits a warm-up drift of approximately 3 μ V to 5 μ V in the negative direction. There are two factors that work together to cause this. Firstly, as the die becomes warm, a temperature gradient forms between pin 2 and pins 1 and 16. Secondly, a thermocouple is created between the metal of the leadframe and the metal of the wire (usually copper) used to connect the IC to a circuit. It takes about 6 minutes for the drift to stabilize. The N and M packages do not exhibit this drift because their leadframes are 90% copper.

Note 10: Human body model, 100 pF discharged through 1.5 k Ω .



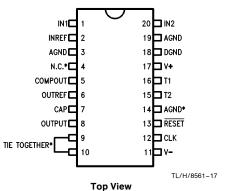
Connection Diagram

16-Pin Dual-In-Line Package



Order Number LMC669D See NS Package Number D16C

20-Pin Dual-In-Line (N) Package 20-Pin Small-Outline (M) Package



2 (2)

Pin Description LMC669 Numbers in () are for 16-pin package

PIN	Description
IN1, IN2	These are the inputs to the Auto Zero's
1, 20	comparator. They should be tied together
(1, 16)	and connected to the summing node of the
	host operational amplifier (op amp). One set
	of inputs, either IN1 and IN2 or INREF, must
	be between $+2$ volts and ground while the
	other can go to V+ (also refer to notes 3
	and 5).

Description **INREF** This is the input for the comparator's

reference voltage. Correction of V_{os} is accomplished by connecting this pin to a good clean system ground of its own. One set of inputs, either IN1 and IN2 or INREF, must be between +2 volts and ground while the other can go to V⁺ (also refer to notes 3 and 5).

^{*}These pins must be connected as shown to ensure compatibility with future parts.

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Pin Desci	ription 16-pin LMC669 (Continued)							
Pin	Description	Pin	Description					
AGND	These act to shield the IN1, IN2, and	These pins select one of five clock						
3,19	INREF connections from stray	T1, T2 These pins select one of fi 16, 15 divider ratios. The ratio, he				e the		
(3,15)	capacitance and leakage which could	(12, 11)	sample	sample rate can be changed by				
	degrade the part's performance. They		applying V+ or ground to T1 and T2.					
	should be connected to a high quality		The rati	o chosei	n by these inp	outs is		
	ground.		valid aft	valid after the comparator's output				
DGND	Provides a separate ground for the		•		.e., a zero-cro	•		
18	internal digital circuitry to prevent noise				set and corre			
(14)	from corrupting the comparator inputs.		voltage has taken place. These			•		
	It should have its own ground		can also be changed at any time to					
COMPOUT	connection.				2669's sample rate. Use			
COMPOUT	This is the latched output from the			the table below to determine the				
5	internal comparator. It is an open drain which can be left unconnected if not			reduction in the clock's frequency for each combination of T1 and T2.				
(4)	needed. Its response time is equal to		T1	T2	RESET	÷		
	the sample rate's period. The rise time,					 		
	from 10% to 90%, is nominally 500 ns		X	X	0	1		
	with a 10 $k\Omega$ pull-up resistor. The output		1 1	1	1	4		
	is typically capable of swinging from		0	0	1 1	16 128		
	+ 0.25 (at 1 mA) to $+ 25$ volts.		0	0		1024		
OUTREF	Output reference; for proper integrator	N/ L N/	-	-				
6	operation this input should be	V+, V-	Positive and negative power supply					
(5)	connected to a good system ground,	17, 11	inputs. Typical supply voltages are ±15					
	such as the ground to which INREF is	(13, 8)	volts, but operation will take place from \pm 8 to \pm 20 volts. Power supply current					
OUTPUT	connected.					•		
8	This is the LMC669's integrator output. It can swing from -12 to $+12$ volts in		is typically 3 mA. Bypass capacitors (0.01 \sim 0.1 μ F) should be connected					
(7)	0.2 volt steps with a \geq 10 K Ω load and		to the power supply pins.					
(1)	no external integrating capacitor.							
CAP	When a capacitor is used to decrease	Applicati	on Hints	3				
7	the correction voltage's step size, it is	1.0 INTRODUCTION						
(6)	connected between CAP and OUTPUT.							
. ,	It parallels an internal 10 pF capacitor.	In its standard application shown in <i>Figure 1</i> , the LMC669 continuously samples the summing node of an inverting am-						
CLK	External clock input/internal adjust.	continuously samples the summing node of an inverting amplifier and generates a correction voltage for the amplifier's non-inverting input, nulling the amplifier's input offset voltage (V _{os}) to 5 μV. The offset correction is independent of time, temperature, and supply voltage. The LMC669 eliminates the need for initial or periodic offset adjustments,						
12	The frequency of the internal clock							
(9)	(nominally 100 kHz) may be reduced							
	with an external capacitor or an							
	external clock connected to the CLK							
	input. The logic thresholds for this input	compensates for Vos drift due to temperature changes, al-						

lows the use of greater DC gain, and increases immunity to changes in power supply voltages.

At the input of the LMC669 is a sampled-data differential comparator with very low offset voltage. When the comparator samples the summing node voltage and determines that it is not at ground, the LMC669's output generates a small voltage step in the opposite direction of the error. The size of the step and the sample rate are user-selectable. The correction voltage continues to step up or down until the summing node is within the $V_{\mbox{OS}}$ of the LMC669—typically 5 μ V. At this point the Auto Zero continues to monitor the summing node and perform any needed corrections. An internal divider generates five different sampling rates for any given clock frequency.

The only external parts needed for V_{os} correction of most amplifiers are two resistors and one capacitor. Since the capacitor is in the feedback loop of an integrator, it should be a low leakage type (polycarbonate, polypropylene, polystyrene, mylar, etc.). The tolerance of the resistors and capacitor is not critical (10% components are satisfactory).

are 4 volts for a logic high and 1 volt for

logic low. The internal clock can be

stopped by applying a logic high,

through a diode, to the CLK input.

When a logic low is applied to the

(See Figure 3)

RESET

13

(10)

9, 10

14

diode, the internal clock runs freely.

Comparator reset. At power-up, or

when RESET is pulled low during

for the quickest Vos nulling.

Leave this pin unconnected.

Connect these pins together.

Connect to analog ground.

normal operation, the Auto Zero will run

at its fastest sample rate. This allows

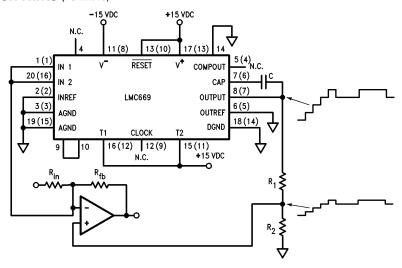


FIGURE 1. Typical Application

1.1 CIRCUIT OPERATION

At the heart of the LMC669 is a four-stage precision sampled-data comparator, shown in *Figure 2*. The circuit operates by successively zeroing the offset of each stage, resulting in a very high gain amplifier with extremely low input offset voltage.

After a comparator decision is made, the latch is enabled and holds the comparator's output state. At the same time this state appears at COMPOUT. The latch also generates a $\pm\,1\text{V}$ signal that charges capacitor C_1 to $\pm\,1\text{V}$. C_1 's charge is then transferred to the integrator's feedback capacitor C_2 . Since C_2 is five times larger than C_1 , a 200 mV step will appear at the integrator's output. Further reduction of the step size is possible with an external capacitor connected in parallel with C_2 (between OUTPUT and CAP). The integrator output is then attenuated by a resistive divider network before being applied to the external op amp's non-inverting input, completing the offset correction loop.

1.2 CLOCKS

In order to control the events that take place in the LMC669, an internal Schmitt trigger oscillator generates a 100 kHz clock. This oscillator's frequency can be lowered by connecting a capacitor between the CLK input and ground as in Figure 3c. It can also be overridden by applying an external clock source (\leq 100 kHz) to the CLK input (Figure 3a). Further, the clock can be halted with a diode connected as shown in Figure 3(b).

The clock signal drives the input of the divider (See *Figure 2*). Depending on the logic levels at inputs T1, T2, and RESET, the clock can be divided by five different ratios (1, 4, 16, 128, and 1024). The output of the divider triggers the sequencer which controls the auto-zero function.

TL/H/8561-5

When the LMC669 is powered-up or reset the internal divider automatically divides by one. This allows the Auto-Zero to operate at maximum sampling rate so that large initial offsets can be rapidly corrected. When the comparator toggles for the first time, this indicates that input null has been achieved and that maximum sample rate is no longer required. The latch then switches the divider from \div 1 to the ratio programmed via T1 and T2. By employing this "two speed" approach the device can move quickly to handle turn-on transients and then shift to the optimum "gear" for long term offset correction. It is also possible to return to the maximum sample rate via the $\overline{\text{RESET}}$ input so that non-power-up transients can be dealt with as well.

1.3 INPUT RANGE

The IN1, IN2, and INREF inputs can accept signal levels between 0 and ± 2 V. However, as long as both IN1 and IN2, or INREF, is kept between 0 and 2V the other input (or inputs) can be taken to V $^+$ and, if input current limiting (≤ 20 mA) is provided, to V $^-$. In most auto-zero applications IN1 and IN2 will be able to go to these extended limits since INREF will normally be grounded.

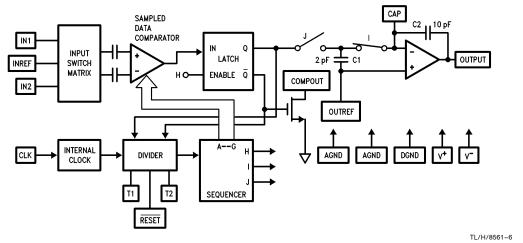


FIGURE 2. Block Diagram

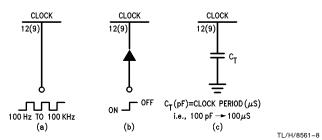


FIGURE 3. Clock Input. External clock (a), controlling internal clock (b), reducing internal clock frequency (c).

2.0 APPLICATION CIRCUITS

The most general application of the Auto-Zero is offset correction of an inverting op amp as shown in Figure 1. The example below shows how the integration capacitor and the resistor divider are chosen

Determine the maximum expected offset voltage from the op amp characteristics and the requirements of the overall system. The correction voltage swing capability should be greater than or equal to this value. Also select the minimum system resolution and the time that can be allowed to null the initial offset. These will determine the correction voltage step size. The magnitude of the correction voltage (V_{corr}) and the step size (dv) are defined according to equations 1

Correction voltage =
$$V_{corr} = V_{out} \frac{R_2}{R_1 + R_2}$$
 (1)

 V_{0} is typically $\pm\,12V$ for $\pm\,15V$ supplies.

$$R_2 = \frac{R_1 V_{corr}}{(V_0 - V_{corr})}$$

$$= \frac{10K V_{corr}}{(12 - V_{corr})}$$
(1a)

for R $_1 \,=\,$ 10 $k\Omega$ (For proper operation R $_1 \,+\,$ R $_2$ should be greater than 10 k Ω .)

be greater than 10 kft.)

step size =
$$dv = 1.0V \left(\frac{C_1}{C_2 + C}\right) \left(\frac{R_2}{R_1 + R_2}\right)$$
 (2)

$$C = \frac{C_1 R_2}{dv (R_1 + R_2)} - C_2$$
 (2a)

$$C = \frac{C_1 R_2}{dv (R_1 + R_2)} - C_2 \tag{2a}$$

with $C_1=2$ pF, $C_2=10$ pF, R_1 and R_2 from Eq. 1a. C_1 and C_2 are internal.

A further consideration regarding the selection of step size is resolution: the magnitude of the smallest significant signal. In the case of nulling the Vos of an op amp used with a digital-to-analog converter (DAC) the smallest signal is the voltage produced by the least-significant bit (LSB). Therefore, the correction voltage's step size would need to be much smaller than the magnitude of the DAC's LSB in order to retain the DAC's desired resolution.

Finally, for proper operation, the sampling period should be longer than the amplifier's settling time. 10 µs or more should be adequate for most contemporary amplifiers.

DESIGN EXAMPLE

As an example, assume that the offset of the op amp in Figure 1 is expected to be no more than 15 mV and the system can tolerate a 1 μV square wave at a rate equal to the internal clock. Begin by using R_1 and R_2 to set the maximum correction voltage to 15 mV. The LMC669's output can swing to \pm 12 volts with a 10 K Ω load and a \pm 15 volt power supply. R₁ and R₂ should be chosen to reduce this to

$$\begin{split} R_2 &= \frac{R_1 \, V_{corr}}{V_o - V_{corr}} \\ &= \frac{(10 \text{K}) \, (0.015)}{(12 - 0.015)} \\ &= 12.5 \Omega \, \approx \, 13 \Omega \\ &\text{for } \pm 15 \text{V supplies and R}_1 \, = \, 10 \text{K}. \end{split}$$

Now choose C, the integrator's external feedback capacitor, to set the final step size to 1 μ V. Using equation (2a):

$$C = \frac{C_1 R_2}{\text{dv}(R_1 + R_2)} - C_2$$
 with $R_1 = 10 \text{ k}\Omega$, $R_2 = 13\Omega$, $C_1 = 2 \text{ pF}$, and $C_2 = 10 \text{ pF}$, yields
$$C \cong 2500 \text{ pF}$$

The null time for this example, with an amplifier offset of 15 mV, step size of 1 μ V, and initial sample rate of 100 kHz, is

Null time =
$$\frac{V_{os}}{(dv)(sample rate)}$$
 (3)
= 150 msec

If this is too slow, the step size can be increased.

OP AMP INPUT BIAS CURRENT

Input bias current should be considered when selecting an op amp that is nulled by the LMC669. If this current is too high, the result is a significant voltage drop across the feedback components and consequent output offset. The Auto Zero will not correct this error since it does not appear as a voltage at the summing node. Therefore, use low resistance feedback networks, or op amps with low input bias current such as the LF156, LF400, and LF411.

NOISE

Through careful selection of the sample rate and step size a compromise can be made between noise and null time. Low sample rates achieve low noise but take a long time to null an offset or correct it when a sudden change occurs. High sample rates can quickly null or correct changes in Vos but do so with an increase in noise. Step size directly affects the null time and the amount of noise introduced: small step sizes (< 100 nV) contribute almost no noise, but result in long null times.

Low noise LMC669 applications are beneficial to instrumentation and audio electronics. An LM833 low noise operational amplifier (4.5 nV /V Hz) with the LMC669 is shown in Figure 4. In this circuit the Auto Zero adds only 1 nV $/\sqrt{\text{Hz}}$ referred to the amplifier's input. To achieve this the step size is set to 100 nV. The sample rate, with the internal clock free-running, is set to 98 Hz (clock frequency ÷ 1024), and input and output filters are added to the LMC669. The input filter prevents switching transients from reaching the amplifier input and the output filter attenuates AC components of the steps at the Auto Zero's output. The filter at the op amp's input also introduces a pole at

$$F_p = \frac{1}{2\pi (R_{in} + R_f) C_f}$$

and a zero at

$$F_z = \frac{1}{2\pi R_f C_f}$$

The maximum V_{os} that can be corrected by the circuit in Figure 4 is 12 mV. More offset correction can be obtained while retaining good noise performance by increasing the size of R2 and C the same percentage. Increasing C compensates for the reduced attenuation caused by increasing R2. This allows the step size to remain the same but increases the amount of correction voltage applied to the op

Application Hints (Continued) +15 VDC N.C. 13 (10) RESET 1|²⁰⁰⁰ pF 20 (16) IN 2 CAP INREF OUTPUT LMC669 6 (5) AGND OUTREF 18 (14) 19 (15) DGND CLOCK **≶** 5.1 kΩ 16(12) 12(9) 15 (11) N.C. R_{fb} 5.1 kΩ 10Ω ≸ TL/H/8561-9 FIGURE 4. Low Noise Application -15 VDC +15 VDC N.C. 13 (10) RESET COMPOUT 1 C 2000 pF 20 (16) IN 2 2 (2 OUTPUT INREF LMC669 3 (3 OUTREF AGND 18 (14) DGND CLOCK 15 (11) +15 VDC 16(12) 12(9) N.C. R_{fb} ✓✓ $R_1 \lessgtr 10\,k\Omega$ $R_2 \ge 10\Omega$ TL/H/8561-10 FIGURE 5. Zeroing LM1875 Power Op-Amp

POWER AMPLIFIERS

For applications such as motor control, automated servo systems, and power amplification the LMC669 can also be used with amplifiers other than standard small signal op amps. *Figure 5* shows how the Auto Zero can allow an LM1875 audio power amplifier to operate with very low offset. While the sample rate for this configuration is not critical, the LMC669's output step size should be set for less than 1 μ V to ensure low system noise.

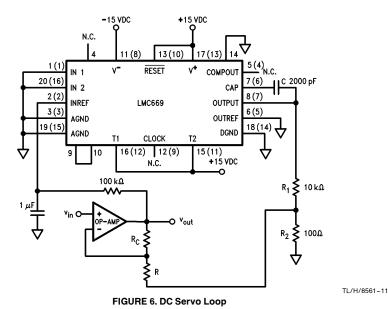
NON-INVERTING AMPLIFIERS AND SYSTEMS

A variation of the above circuit appears in Figure 6 with the LMC669 operating as a DC-servo integrating feedback loop. This configuration is applicable when the Auto Zero is used with non-inverting op amps amplifying AC-only signals. The output error of the amplifier is reduced to the V_{os} of the Auto Zero, typically 5 μV . A filter at the input of the LMC669 limits current and ensures that only DC and very low frequencies

(< 0.6 Hz) are sampled. In this application the output of the op amp is sampled and compared with a reference ground. The correction output from the Auto Zero now replaces the ground reference for the feedback resistor connected to the inverting input.

Systems can also benefit from the Auto Zero. Figure 7 shows how the $V_{\rm OS}$ of an MF6 Butterworth low-pass switched capacitor filter is nulled by the LMC669. The Auto Zero's IN1 and IN2 inputs are connected to the MF6's output while INREF is connected to its input. The correction signal is applied to the MF6's $V_{\rm OS}$ ADJ input. RC low-pass filters (Rf1, Cf1 and Rf2, Cf2) are used to reduce AC signals at the LMC669's inputs and provide current limiting. It is important to set each passive RC filter's cutoff as low as possible, at most 0.1 of the MF6's $f_{\rm O}$.

This correction makes the MF6 useful in applications calling for good DC accuracy. The MF6's typical 250 mV offset is decreased to 5 μ V with a step size of 1 μ V.



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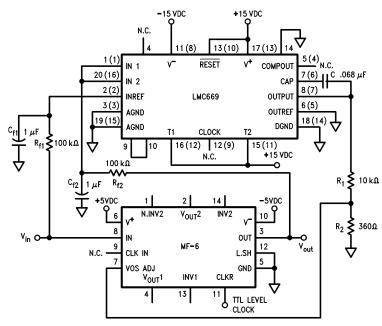


FIGURE 7. Auto zeroing a system. In this case the 250 mV offset of a switched-capacitor low-pass filter is corrected by the LMC669.

MAINTAINING DAC LINEARITY

The LMC669 is particularly useful for zeroing the offset of an op amp used with a CMOS digital-to-analog converter (DAC). For good linearity the DAC's two outputs (Iout and lout) must be connected to identical ground potentials. The presence of op amp Vos (and its drift due to temperature) will degrade the DAC's linearity. Even though the effects of Vos can be corrected by trimming, a static trim will not be very helpful if the Vos changes with respect to temperature. Figure 8 shows the DAC1208 with a 10V reference driving an LF357. The linearity of this DAC will degrade by 0.01% for each millivolt of op amp V_{os} . Therefore, the LF357's typical offset of 5 mV will turn the 12-bit DAC1208's 0.012% linearity error into 0.062%. What was a 12 bit linear device now has only 9 bits linearity. The original linearity specification can be retained by connecting an LMC669 to the inputs of the LF357, rendering the non-linearity due to V_{os} and temperature drift negligible. The DAC is now able to operate at its published linearity specifications independent of Vos and temperature.

Figure 9 shows the schematic of a unipolar power DAC. One use of the power DAC is as a digitally controlled power supply having the ability to sink current, in the case of inductive loads, as well as source current. The linearity of the DAC is preserved by the nulling action of the LMC669 connected to the inputs of the LM1875 power amplifier. The

amplifier can generate an output voltage from 0 to 25 volts and a maximum current of 3 amperes. The actual output is determined by

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$$V_{out} = \frac{-V_{ref} \text{ (D)}}{4096}$$

("D" is the value of the digital code, base 10). The magnitude of each step is

$$1 LSB = \frac{|V_{ref}|}{4096}$$

Stable operation of the LM1875 is ensured by the RC combination connected to the inverting input.

LMC669 AS A COMPARATOR

The LMC669's operation as a comparator is shown in Figure 10. Its input impedance is 5 k Ω with 160 pF to ground. For proper operation as a comparator IN1 and IN2, or IN-REF, should be kept between 0 and 2V while the other input (or inputs) can be taken to V⁺. If input current limiting (\leq 20 mA) is provided, the inputs can also go to V⁻. (In addition, please refer to notes 3 and 5 under "Electrical Characteristics".)

The open collector output can be pulled-up to typically 25 volts. When the sink current is 1 mA the output can pull-down to 0.25V. Outputs closer to ground are possible with a larger pullup resistor.

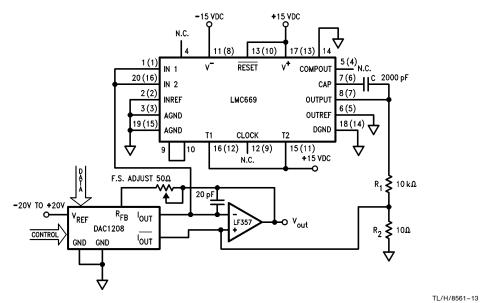


FIGURE 8. Reducing $\rm V_{os}\textsc{-}induced$ linearity errors in a 12-bit DAC by 0.01% /mV offset.

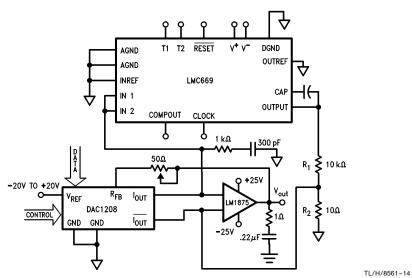
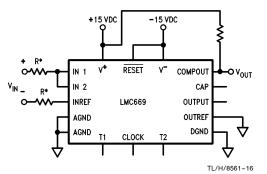


FIGURE 9. Power DAC with $\pm\,20\text{V}_{\text{p-p}}$ and 3A output capabilities.

LOW-FREQUENCY, HIGH-GAIN AMPLIFIER

For applications that require precision high-gain DC and low-frequency performance, the LMC669 can be connected as an amplifier as shown in Figure 11. For a closed-loop gain of -1000 the useful frequency range is typically

$$F_{\text{max}} = 20 \frac{\text{Hz}}{\text{mV of step size}}$$



*R = 10K. For inputs greater than 2 volts.

FIGURE 10. Low-Speed Precision Comparator

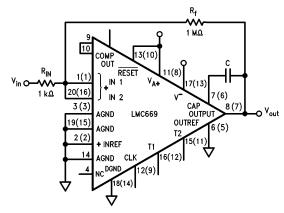
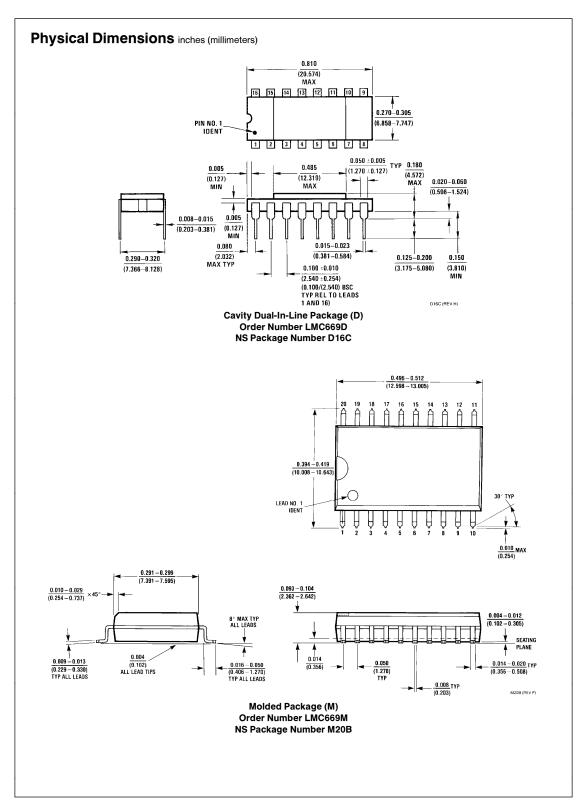


FIGURE 11. Low Offset, High Gain, Low Frequency Op Amp.

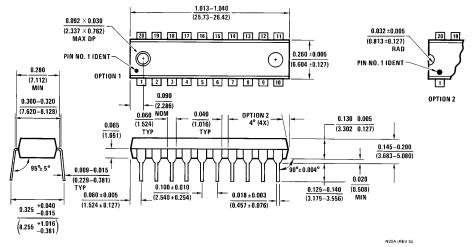
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$$Bandwidth \, \cong \, 20 \, \frac{Hz}{mV \, of \, step \, size}, sample \, rate \, = \, 100 \, kHz.$$



Physical Dimensions inches (millimeters) (Continued)

Lit. # 108455



Molded Dual-In-Line Package (N) Order Number LMC669N NS Package Number N20A

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